

### Features

- Low operating voltage: 36V
- Ultra low capacitance: 4pF
- Ultra low leakage: nA level
- Low clamping voltage
- -IEC 61000-4-2 (ESD) immunity test  
Air discharge:  $\pm 20\text{kV}$   
Contact discharge:  $\pm 20\text{kV}$
- -IEC61000-4-4 (EFT) 40A (5/50ns)
- 3-pin leadless package
- These are Pb-Free Devices
- Response Time is Typically  $< 1\text{ ns}$

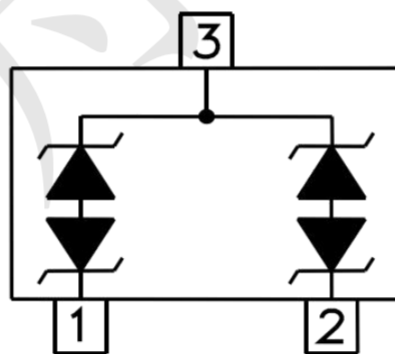
### Mechanical Characteristics

- Package: SOT-23
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound
- Terminal Connections: See Diagram Below
- -IEC 61000-4-2 (ESD) immunity test

### Applications

- Industrial Controls
- Personal Digital Assistants
- Notebooks and Handhelds
- CAN Bus Protection
- Automotive Appllcatrons

### Dimensions and Pin Configuration



**SOT-23**

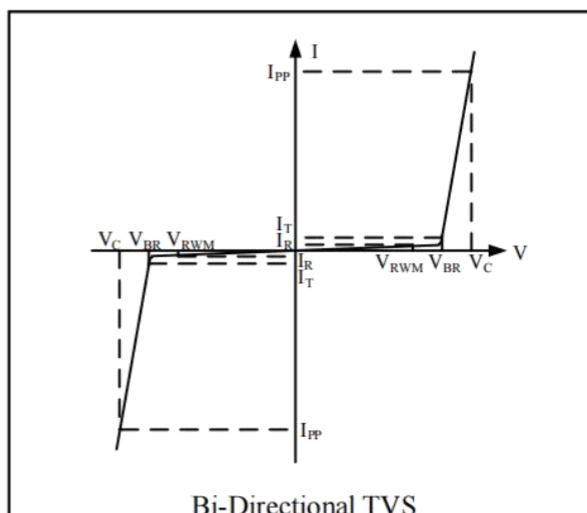
### Absolute Maximum Ratings (T<sub>amb</sub>=25°C unless otherwise specified)

| Parameter                                                      | Symbol           | Value       | Unit |
|----------------------------------------------------------------|------------------|-------------|------|
| Peak Pulse Power (8/20μs)                                      | P <sub>pk</sub>  | 150         | W    |
| IEC 61000-4-2 Spec Current at 60 ns (A)                        | I <sub>pp</sub>  | 2           | A    |
| ESD per IEC 61000-4-2 (Air)<br>ESD per IEC 61000-4-2 (Contact) | V <sub>ESD</sub> | ±20<br>±20  | KV   |
| Operating Temperature Range                                    | T <sub>J</sub>   | -55 to +125 | °C   |
| Storage Temperature Range                                      | T <sub>stg</sub> | -55 to +150 | °C   |

### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

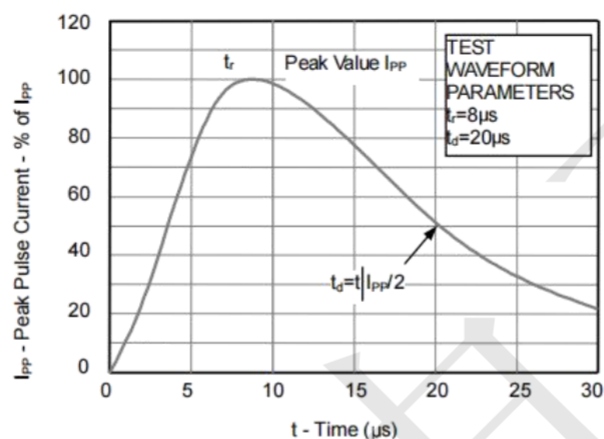
| Parameter               | Symbol           | Min | Typ | Max | Unit | Test Condition                              |
|-------------------------|------------------|-----|-----|-----|------|---------------------------------------------|
| Reverse Working Voltage | V <sub>RWM</sub> | --  | --  | 36  | V    |                                             |
| Breakdown Voltage       | V <sub>BR</sub>  | 38  | --  | 44  | V    | I <sub>T</sub> = 1mA                        |
| Reverse Leakage Current | I <sub>R</sub>   | --  | --  | 0.1 | μA   | V <sub>RWM</sub> =36V                       |
| Clamping Voltage        | V <sub>C</sub>   | --  | 45  | 51  | V    | I <sub>pp</sub> =1A(8x 20us pulse)          |
| Clamping Voltage        | V <sub>C</sub>   | --  | 64  | 72  | V    | I <sub>pp</sub> =2A(8x 20us pulse)          |
| Junction Capacitance    | C <sub>J</sub>   | --  | 10  | --  | pF   | V <sub>R</sub> =0V, f =1MHz, Pin1,2 to Pin3 |
| Junction Capacitance    | C <sub>J</sub>   | --  | 3   | 6   | pF   | V <sub>R</sub> =0V, f =1MHz, Pin1, to Pin2  |

| Symbol           | Parameter                                  |
|------------------|--------------------------------------------|
| V <sub>RWM</sub> | Nominal Reverse Working Voltage            |
| I <sub>R</sub>   | Reverse Leakage Current @ V <sub>RWM</sub> |
| V <sub>BR</sub>  | Reverse Breakdown Voltage @ I <sub>T</sub> |
| I <sub>T</sub>   | Test Current for Reverse Breakdown         |
| V <sub>C</sub>   | Clamping Voltage @ I <sub>pp</sub>         |
| I <sub>pp</sub>  | Maximum Peak Pulse Current                 |
| C <sub>ESD</sub> | Parasitic Capacitance                      |
| V <sub>R</sub>   | Reverse Voltage                            |
| f                | Small Signal Frequency                     |

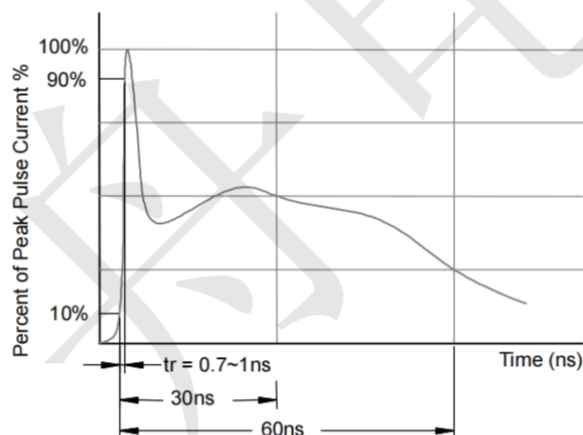


### Characteristic Curves

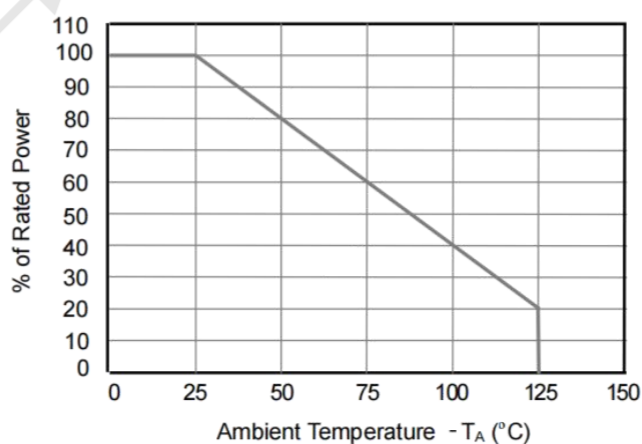
**Fig1. 8/20 $\mu$ s Pulse Waveform**



**Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)**

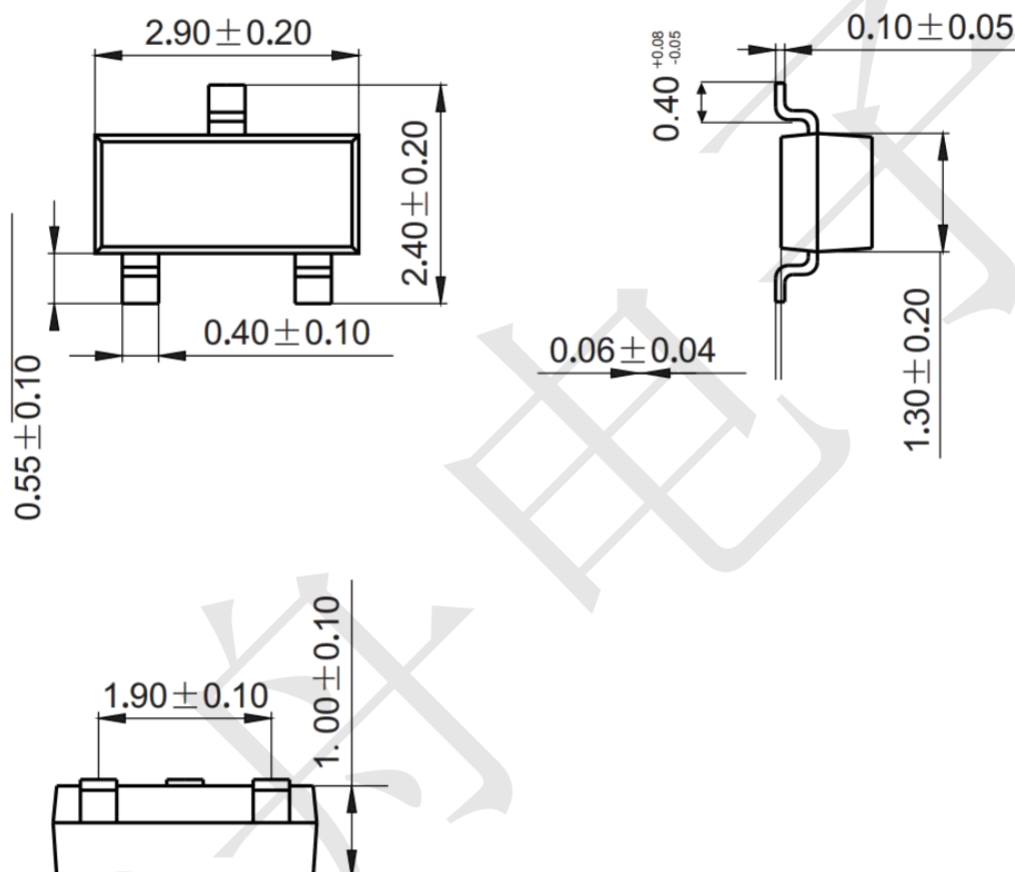


**Fig3. Power Derating Curve**



## Package Outline Dimensions (unit: mm)

### SOT-23



## Mounting Pad Layout (unit: mm)

